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Features

- 32-kHz Voltage Regulated Oscillator
- 1.1 V to 2.2 V Operating-voltage Range
- Integrated Capacitors for Digital Trimming
- Suitable for up to 12.5 pF Quartz
- Trimming Inputs Insenitive to Stray Capacitance
- Output Pulse Formers
- Mask Options for Motor Period and Pulse Width
- Low Resistance Output for Bipolar Stepping Motor
- Motor Fast-test Function

Description

The e1467D is an integrated circuit in CMOS Silicon Gate Technology for analog clocks. It consists of a 32-kHz oscillator, frequency divider, output pulse formers, push-pull motor drivers and alarm output. Integrated capacitors are mask-selectable to accomodate the external quartz crystal. Additional capacitance can be selected through pad bonding to trimming the oscillator frequency.



32-kHz Clock CMOS IC with Digital Trimming and Alarm

e1467D





Pad Configuration

Figure 1. Pad Configuration

SC4 SC3 SC2 SC1 VDD⁽¹⁾ 1 13 12 11 10 9 OSCIN vss OSCOUT(1) 2 8 e1467D 7 **ALOUT** ALIN / MOT2 6 3 MTEST(2) MOT1L(2) 4 MOT1R

Pin Description

Name	Description				
VDD	Positive supply voltage				
VSS	Negative supply voltage				
OSCIN	Oscillator input				
OSCOUT	Oscillator output				
MOT1/2	Motor drive outputs				
ALIN	Alarm input				
ALOUT	Alarm output				
SC1 SC4	Oscillator trimming inputs				

⁽¹⁾ The pads VDD and OSCOUT are interchangeable per mask option

⁽²⁾ The pads for ALIN/-MTEST and MOT1L are interchangeable per mask option

Functional Descripion

Oscillator

An oscillator inverter with feedback resistor is provided to generate the 32768 Hz clock frequency. Values for the fixed capacitors at OSCIN and OSCOUT are mask-selectable (see note 3 of "Operating Characteristics"). Four control inputs, SC1 to SC4, enable the users to add integrated trimming capacitors to OSCIN and OSCOUT, providing 15 tuning steps.

A frequency variation of typically 4 ppm for each tuning step is obtained by bonding the capacitor pads to OSCIN. As none of these pads are bonded, the IC is in an untrimmed state. Figure 2 shows the trimming curve characteristic.

Note: For applications which utilize this integrated trimming feature, Atmel will determine optimum values for the integrated capacitors C_{OSCIN} and C_{OSCOUT} .

Motor Drive Output

The e1467D contains two push-pull output buffers for driving bipolar stepping motors. During a motor pulse, the N-channel device of one buffer and the P-channel device of the other buffer will be activated. Both N-channel transistors are on and conducting between output pulses. The outputs are protected against inductive voltage spikes with diodes to both supply pins. The motor output period and pulse width are mask-programmable, as listed below:

Available motor periods (T_M): 125, 250, 500 ms and 2, 16 s

Available maximum pulse widths (t_M): 15, 6, 23.4, 31.25, 46.9 ms

Available motor periods for motor test (T_{MT}) : 250, 500 ms and 1 s

Note: The following constraints for combination of motor period and pulse widths have to be considered: $T_M > 4 \times t_M$, $T_{MT} > 4 \times t_M$ or alternatively $T_M = 2 \times t_M$, $T_{MT} = 2 \times t_M$

Alarm Outputs

The alarm output driver consists of a push-pull stage for driving a speaker via an external bipolar transistor. The output is configured for NPN and PNP bipolar capability. The output is an alarm tone, modulated by a low frequency. Tone frequencies, modulation frequencies, and on/off times are selectable via the metal mask option.

Alarm Input

A debounced alarm input is provided. Alarm activation is connected either to V_{DD} or V_{SS} by a mask option.

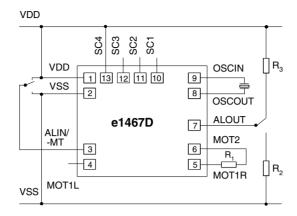
Test Functions

For test purposes, the TEST pad is open. With a high resistance probe (R \geq 10 M Ω , C \geq 20 pF), a test frequency f_{TEST} of 128 Hz can be measured at the ALIN/MTEST pad. Connecting ALIN/MTEST (for at least 32 ms) to the opposite polarity for alarm activation changes the motor period from the selected value to T_{MT} (mask-selectable) while the pulse width remains unaffected. This feature can be used for testing the mechanical parts of the clock.





Figure 2. Functional Test



Test Crystal Specification

Oscillation frequency $f_{OSC} = 32768 \text{ Hz}$ Series resistance $R_S = 30 \text{ k}\Omega$

Static capacitance $C_0 = 1.5 \text{ pF}$ Dynamic capacitance $C_1 = 3.0 \text{ fF}$

Load capacitance C_L optionally 10 or 12.5 pF

Absolute Maximum Ratings

Absolute maximum ratings define parameter limits which, if exceeded, may permanently change or damage the device. All inputs and outputs on Atmel's circuits are protected against electrostatic discharges. However, precautions to minimize the build-up of electrostatic charges during handling are recommended.

The circuit is protected against supply voltage reversal for typically 5 minutes.

Parameters	Symbol	Value	Unit
Supply voltage	V _{SS}	-0.3 to 5 V	V
Input voltage range, all inputs	V _{IN}	$(V_{SS} - 0.3 V) \le V_{IN} \le (V_{DD} + 0.3 V)$	V
Output short circuit duration		indefinite	
Power dissipation (DIL package)	P _{tot}	125	mW
Operating ambient temperature range	T _{amb}	-20 to +70	°C
Storage temperature range	T _{stg}	-40 to +125	°C
Lead temperature during soldering at 2 mm distance, 10 s	T _{sld}	260	°C

Operating Characteristics

 $V_{SS} = 0$ V, $V_{DD} = 1.5$ V, $T_{amb} = +25^{\circ}$ C, unless otherwise specified. All voltage levels are measured with reference to V_{SS} . Test crystal as specified below.

Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit	
Operating voltage		V_{DD}	1.1	1.5	2.2	V	
Operating temperature		T _{amb}	-20		+70	°C	
Operating current	$R_1 = \infty^{(2)}$	I _{DD}		1	3	μΑ	
Motor Drive Output		•	•	•	•		
Motor output current	$V_{DD} = 1.2 \text{ V}, R_1 = 200 \Omega$	I _M	±4.3			mA	
Motor period		T _M	S	ee option I	ist	S	
Motor period during motor test		T _{MT}	See option list				
Motor pulse width		t _M	S	ee option I	ist	ms	
Oscillator							
Start-up voltage	Within 2 s	V _{START}	1.2		2.2	V	
Frequency stability	$\Delta V_{DD} = 100 \text{ mV}, V_{DD} = 1.1 \text{ to } 2.2 \text{ V}$	Δf/f		0.1	0.2	ppm	
Integrated input capacitance	(3)	C _{OSCIN}	See option list			pF	
Integrated output capacitance		C _{OSCOUT}	See option list			pF	
Input current SC1 to SC4	$V_{IN} = 0.2 \text{ V}$ $V_{IN} = V_{DD}^{(5)}$	I _{SCINL} I _{SCINH}	1 5 0.05 0.15		25 0.5	μΑ μΑ	
Alarm/Output		•	•	•	•		
Output current for driving npn transistor	V _{DD} = 1.2 V						
N-channel	$R_3 = 100 \text{ k}\Omega$	I _{ANn}	1	3	10	μΑ	
P-channel	$R_2 = 1 k\Omega^{(2)(4)}$	I _{ANp}	-0.5	-1		mA	
Output current for driving pnp-transistor	V _{DD} = 1.2 V						
N-channel	$R_3 = 1 k\Omega$	I _{APn}	0.5	1		mA	
P-channel	$R_2 = 100 \text{ k}\Omega^{(2)(4)}$	I _{APp}	-1	-2	-10	μΑ	
Alarm Options							
Tone frequency	ne frequency		See option list		Hz		
Modulation frequency		f _{MOD}	See option list			Hz	
On/off time	t _{ON} /t _{OFF}	See option list			S		
Alarm Input/Motor Test							
Input current	ALIN = V _{DD} , peak current	I _{AINH}	0.6	3	10	μΑ	
Input current	ALIN = V _{SS} , peak current	I _{AINL}	-0.6	-3	-10	μΑ	
Input debounce delay		t _{AIN}	23.4		31.2	ms	

- Notes: 1. Typical parameters represent the statistical mean values
 - 2. See test circuit
 - 3. Values can be selected in 1 pF steps. A total capacitance ($C_{OSCIN} + C_{OSCOUT}$) of 38 pF is available
 - 4. NPN or PNP driving transistors defined by mask options
 - 5. I_{SCINH} is the peak current of a pulsed current with a duty cycle of 1:63. Average current is always smaller than 10 nA





Figure 3. Motor Output Signal During Normal Operation and During Motor Test

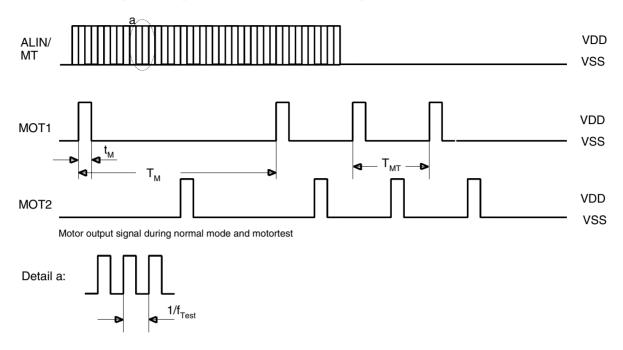
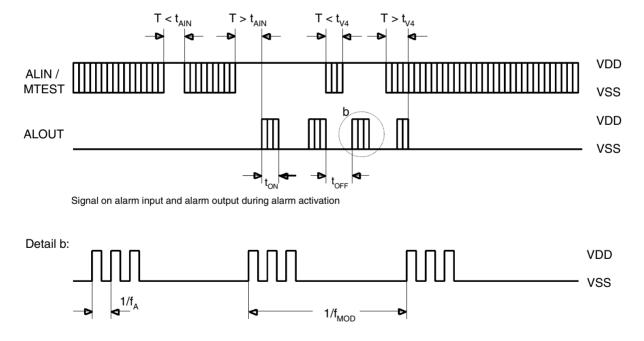


Figure 4. Alarm Operation



Alarm output signal

2.00006 2.00005 COX = 1.05 2.00004 COX = 1.00 2.00003 COX = 0.95 2.00002 2.00001 2.00000 1.99999 1.99998 1.99997 1.99996 1.99995 1.99994 1.99993 1.99992 5 6 7 8 9 Trimming Step 0 1 2 3 4 10 11 12

Figure 5. Typical Trimming Curve Characteristic for T_M of 2 s

 \mathbf{C}_{OX} means frequency deviation due to production process variations.

Trimming inputs SC1 ... SC4 are binary weighted, i.e.,

SC1 ... SC4 = 0 corresponds to trimming step 0

SC1 ... SC4 = 1 corresponds to trimming step 15

LSB = SC1





Ordering Information

Table 1. Option List e1467D

		Motor		Alarm						Integrated Capacitance	
Option	Cycle (T _M) s	Pulse (t _M) ms	e Test (T _{MT}) Frequency Modulation On/off Frequency Time Driver Hz S Type		_	Activation Polarity	pF	C _{OSCIN} ⁽¹⁾ pF	C _{OSCOUT} ⁽¹⁾		
-B	2	23.4	250	2048	8	0.5/0.5	NPN	V_{SS}	10	17	12
-D	2	31.25	250	2048	8	0.5/0.5	NPN	V_{DD}	10	17	12
-V2	0.5	23.4	250	2048	8	0.5/0.5	NPN	V _{SS}	12.5	20	16
E2	2	46.9	250	2048	8	1/3	NPN	V _{SS}	12.5	20	16

Note: 1. On-chip stray capacitance included

	Pad Designation												
Option	Pad 1	Pad 2	Pad 3	Pad 4	Pad 5	Pad 6	Pad 7	Pad 8	Pad 9	Pad 10	Pad 11	Pad 12	Pad 13
-B	OSCIN	V _{DD}	ALOUT	MOT2	MOT1	MOT1	ALIN/ MTEST	V_{SS}	OSCOUT	SC4	SC3	SC2	SC1
-D	OSCIN	OSCOUT	ALOUT	MOT2	MOT1	MOT1	ALIN/ MTEST	V_{SS}	V_{DD}	SC4	SC3	SC2	SC1
-V2	OSCIN	V _{DD}	ALOUT	MOT2	MOT1	MOT1	ALIN/ MTEST	V_{SS}	OSCOUT	SC4	SC3	SC2	SC1
-D	OSCIN	OSCOUT	ALOUT	MOT2	MOT1	ALIN/ TEST	MOT1	V_{SS}	V_{DD}	SC4	SC3	SC2	SC1



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